# **MIC913**



### 350MHz Low-Power SOT23-5 Op Amp

### **General Description**

The MIC913 is a high-speed, operational amplifier. It provides a gain-bandwidth product of 350MHz with a very low, 4.2mA supply current, and features the tiny SOT-23-5 package.

Supply voltage range is from  $\pm 2.5V$  to  $\pm 9V$ , allowing the MIC913 to be used in low-voltage circuits or applications requiring large dynamic range.

The MIC913 requires a minimum gain of +2 or -1 but is stable driving any capacitive load and achieves excellent PSRR, making it much easier to use than most conventional high-speed devices. Low supply voltage, low power consumption, and small packing make the MIC913 ideal for portable equipment. The ability to drive capacitive loads also makes it possible to drive long coaxial cables.

Data sheets and support documentation can be found on Micrel's web site at: www.micrel.com.

### **Features**

- 350MHz gain bandwidth product
- 4.2mA supply current
- SOT23-5 package
- 500V/µs slew rate
- · Drives any capacitive load
- Stable with gain of +2 or -1
- Low distortion

### **Applications**

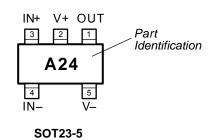
- Video
- Imaging
- Ultrasound
- Portable equipment
- Line drivers
- XDSL

### **Ordering Information**

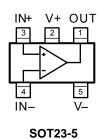
Part Number	Temperature Range	Package	Lead Finish
MIC913BM5	–40° to +85°C	5-Pin SOT23	Standard
MIC913YM5	–40° to +85°C	5-Pin SOT23	Pb-Free

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## **Pin Configuration**



## **Functional Pinout**



## **Pin Description**

Pin Number	Pin Name	Pin Function
1	OUT	Output: Amplifier Output
2	V+	Positive Supply (Input)
3	IN+	Non-inverting Input
4	IN–	Inverting Input
5	V–	Negative Supply (Input)

# Absolute Maximum Ratings<sup>(1)</sup>

Supply Voltage $(V_{V+} - V_{V-})$	20V
Differential Input Voltage $( V_{IN+} - V_{IN-} )^{(3)}$	4V
Input Common-Mode Range (V <sub>IN+</sub> – V <sub>IN-</sub> )	$\dots V_{V^+}$ to $V_{V^-}$
Lead Temperature (soldering, 5 sec.)	260°C
Storage Temperature (T <sub>s</sub> )	150°C
Storage Temperature (T <sub>s</sub> ) ESD Rating <sup>(4)</sup>	1.5kV

# **Operating Ratings**<sup>(2)</sup>

Supply Voltage (V <sub>S</sub> )	±2.5V to ±9V
Junction Temperature (T <sub>J</sub> )	–40°C to +85°C
Thermal Resistance	

## **Electrical Characteristics (±5V)**

 $V_{V^+} = +5V, V_{V_-} = -5V, V_{CM} = 0V, V_{OUT} = 0V; R_L = 10M\Omega; T_J = 25^{\circ}C, \text{ bold } \text{values indicate } -40^{\circ}C \leq T_J \leq +85^{\circ}C; \text{ unless noted.}$ 

Symbol	Parameter	Condition	Min	Тур	Max	Units
Vos	Input Offset Voltage			1	16	mV
	Input Offset Voltage Temperature Coefficient			4		µV/°C
I <sub>B</sub>	Input Bias Current			5.5	9	μA
					15	μA
l <sub>os</sub>	Input Offset Current			0.05	3	μA
V <sub>CM</sub>	Input Common-Mode Range	CMRR > 60dB	-3.25		+3.25	V
CMRR	Common-Mode Rejection Ratio	$-2.0V < V_{CM} < +2.0V$	70	85		dB
PSRR	Power Supply Rejection Ratio	$\pm 5V < V_S < \pm 9V$	70	81		dB
			65			dB
A <sub>VOL</sub>	Large-Signal Voltage Gain	$R_L = 2k, V_{OUT} = \pm 2V$	60	71		dB
		$R_{L} = 200\Omega, V_{OUT} = \pm 2V$	60	71		dB
V <sub>OUT</sub>	Maximum Output Voltage Swing	positive, $R_L = 2k\Omega$	+3.3	3.5		V
			+3.0			V
		negative, $R_L = 2k\Omega$		-3.5	-3.3	V
					-3.0	V
		positive, $R_L = 200\Omega$	+3.0	3.2		V
			+2.75			V
		negative, $R_L = 200\Omega$		-2.8	-2.45	V
					-2.2	V
GBW	Gain-Bandwidth Product	$f = 80MHz, R_L = 1k\Omega$		300		MHz
BW	–3dB Bandwidth	$A_V = 2, R_L = 150\Omega$		213		MHz
		$A_V = 4$ , or $A_V = -3$ , $R_L = 400\Omega$		104		MHz
THD	Total Harmonic Distortion	$R_F = R_G = 470\Omega$ , $A_V = 2$ , $V_{OUT} = 2Vpp$ , f = 2MHz		0.01		%
		$A_V = 2$ , $V_{OUT} = 2Vpp$ , f = 2MHz, $R_L = 500\Omega$		0.05		%
SR	Slew Rate			350		V/µs
	Short-Circuit Output Current	source		72		mA
		sink		25		mA
	Supply Current			4.1	4.9	mA
					5.4	mA

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## **Electrical Characteristics**

Symbol	Parameter	Condition	Min	Тур	Max	Units
V <sub>os</sub>	Input Offset Voltage			1	16	mV
	Input Offset Voltage Temperature Coefficient			4		µV/°C
I <sub>B</sub>	Input Bias Current			5.5	9	μA
					15	μA
l <sub>os</sub>	Input Offset Current			0.05	3	μA
V <sub>CM</sub>	Input Common-Mode Range	CMRR > 60dB	-7.25		+7.25	V
CMRR	Common-Mode Rejection Ratio	$-6.0V < V_{CM} < 6.0V$	70	88		dB
A <sub>VOL</sub>	Large-Signal Voltage Gain	$R_L = 2k\Omega$ , $V_{OUT} = \pm 6V$	60	73		dB
V <sub>OUT</sub>	Maximum Output Voltage Swing	positive, $R_L = 2k\Omega$	+7.2	+7.4		V
			+6.8			V
		negative, $R_L = 2k\Omega$		-7.4	-7.2	V
					-6.8	V
GBW	Gain-Bandwidth Product	$R_L = 1k\Omega$ , f = 80MHz		350		MHz
BW	–3dB Bandwidth	$A_V = 2 \text{ or } A_V = -1, R_L = 150\Omega$		240		MHz
		$A_V = 4 \text{ or } A_V = -3$		140		MHz
THD	Total Harmonic Distortion	$R_F = R_G = 470\Omega$ , $A_V = 2$ , $V_{OUT} = 2Vpp$ , f = 2MHz		0.01		%
		$A_V = 2, V_{OUT} = 2Vpp, f = 2MHz, R_L = 500\Omega$		0.04		%
SR	Slew Rate			500		V/µs
I <sub>GND</sub>	Short-Circuit Output Current	source		90		mA
		sink		32		mA
	Supply Current			4.2	5.0	mA
					5.5	mA

#### Notes:

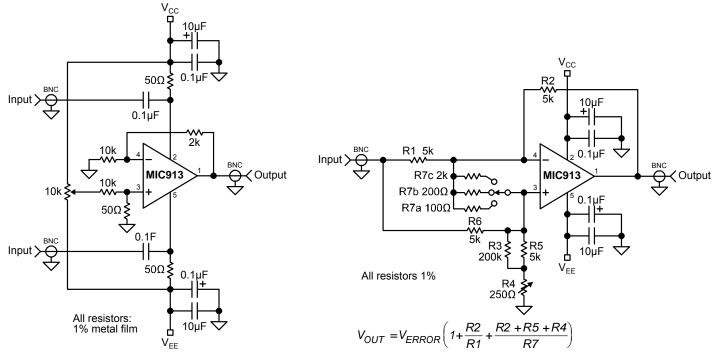
2. The device is not guaranteed to function outside its operating rating.

4. Devices are ESD sensitive. Handling precautions recommended. Human body model, 1.5k in series with 100pF.

<sup>1.</sup> Exceeding the absolute maximum rating may damage the device.

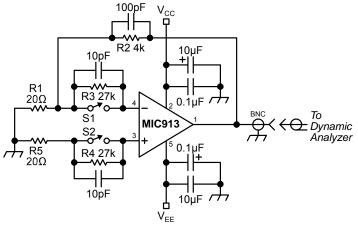
<sup>3.</sup> Exceeding the maximum differential input voltage will damage the input stage and degrade performance (in particular, input bias current is likely to change).

## **Test Circuits**



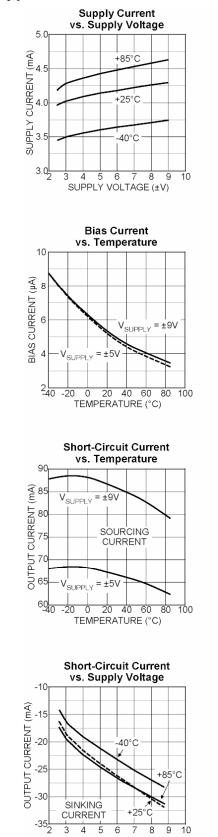
**PSRR vs. Frequency** 

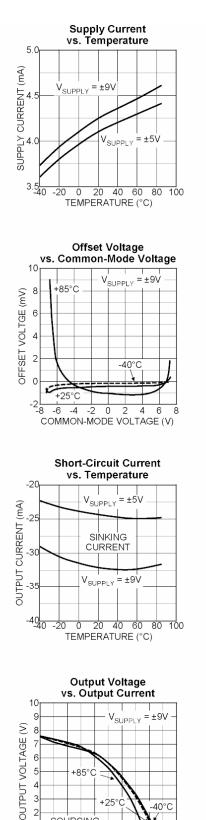
**CMRR vs. Frequency** 

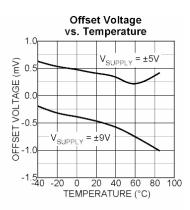


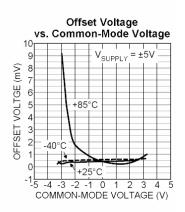
**Noise Measurement** 

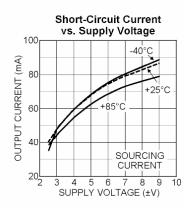
## **Typical Characteristics**

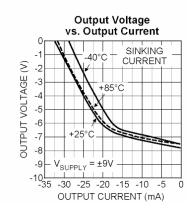












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60

OUTPUT CURRENT (mA)

+25

SOURCING

CURRENT

20 40 -40°C

100

80

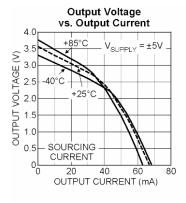
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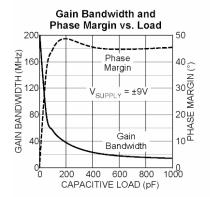
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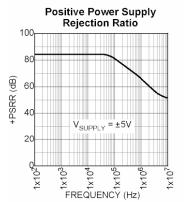
0

SUPPLY VOLTAGE (±V)

## **Typical Characteristics (continued)**

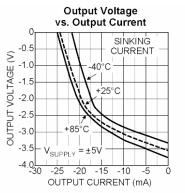






Positive Power Supply Rejection Ratio

FREQUENCY (Hz)



Gain Bandwidth and Phase Margin vs. Supply Voltage 2 (241N BANDWDTH (MHz) 1220 1220 1220 1220 1220 1220 15<sub>€</sub> Gain 0 2 0 PHASE MARGIN Bandwidth 150 Phase Margir 0 100<sup>L</sup> 2 -5 3 4 5 6 7 8 9 SUPPLY VOLTAGE (±V) 3 9 10

Negative Power Supply Rejection Ratio

 $V_{SUPPLY} = \pm 5V$ 

FREQUENCY (Hz)

**Negative Power Supply** 

**Rejection Ratio** 

 $V_{SUPPLY} = \pm 9V$ 

FREQUENCY (Hz)

×10

1×10

1x10<sup>7</sup>

1x10<sup>7</sup>

1×10<sup>c</sup>

1×10

100

80

60

40

20

100

80

60

40

20

1×10<sup>2</sup>P

1×10<sup>-1</sup> 1×10<sup>4</sup>

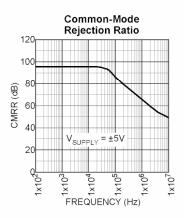
-PSRR (dB)

1×10<sup>2</sup>P

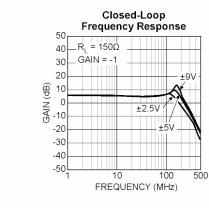
1x10<sup>3</sup>

-PSRR (dB)

Gain Bandwidth and Phase Margin vs. Load 200 50 GAIN BANDWIDTH (MHz Phase 160 Margin 120 V<sub>SUPPLY</sub> = ±5V 80 Gain 40 Bandwidth oL 1000 200 400 600 800 CAPACITIVE LOAD (pF)



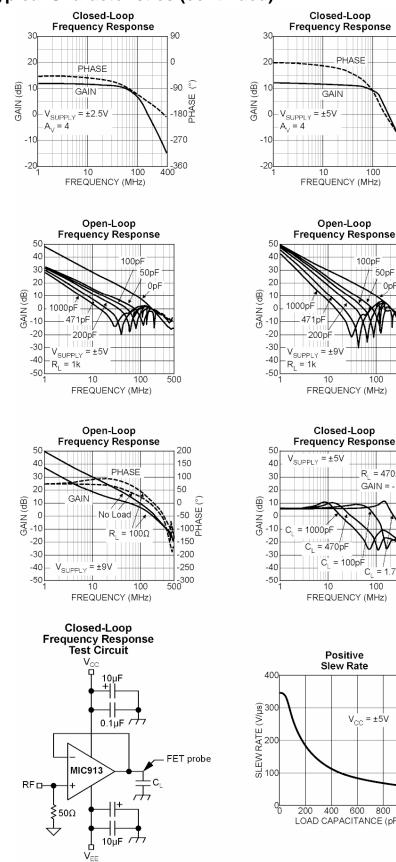
Common-Mode **Rejection Ratio** 120 10 80 CMRR (dB) 60 40 VSUPPLY = ±9V 20 1×10<sup>2</sup> 1×10<sup>7</sup> 1×10<sup>5</sup> 1×10 10, 1×10 X FREQUENCY (Hz)

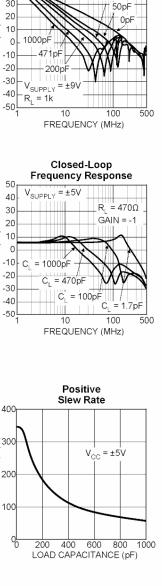


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1×10<sup>5</sup>

### **Typical Characteristics (continued)**





Closed-Loop

GAIN

10

Open-Loop

PHASE

90

0

-90

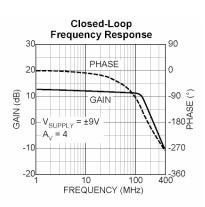
-180H

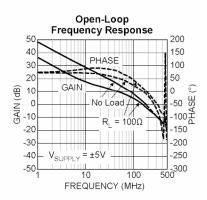
-270

100

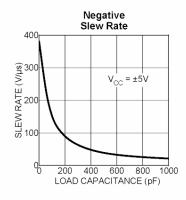
100pF

 $\hat{\phantom{a}}$ 



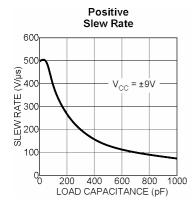


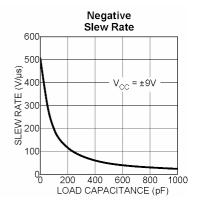
Closed-Loop Frequency Response 50  $V_{SUPPLY} = \pm 9V$ 40 R = 470Ω 30 GAIN = -1 20 GAIN (dB) 10 0 -10 1000pf -20 = 470 pFC -30 = 100pF C, -40  $C_{1} = 1.7 pF$ -50 100 500 FREQUENCY (MHz)

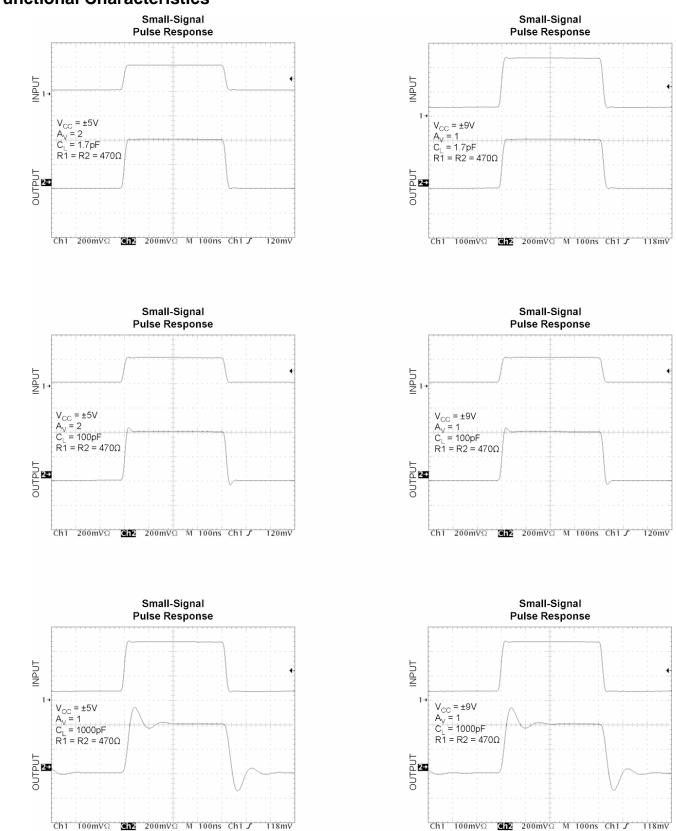


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## **Typical Characteristics (continued)**

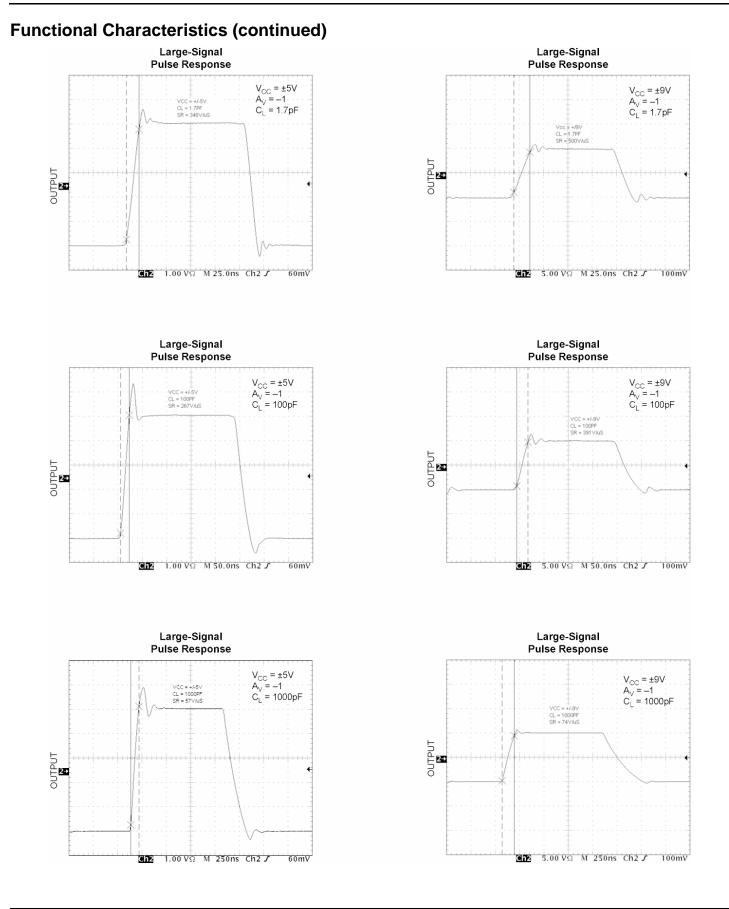






### **Functional Characteristics**

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The MIC913 is a high-speed, voltage-feedback operational amplifier featuring very low supply current. The MIC913 is not unity-gain stable, it requires a minimum gain of +2 or -1 to ensure stability. The device is however stable even when driving high capacitance loads.

#### **Driving High Capacitance**

The MIC913 is stable when driving any capacitance (see "Typical Characteristics: Gain Bandwidth and Phase Margin vs. Load Capacitance") making it ideal for driving long coaxial cables or other high-capacitance loads.

Phase margin remains constant as load capacitance is increased. Most high-speed op amps are only able to drive limited capacitance.

> Note: increasing load capacitance does reduce the speed of the device (see "Typical Characteristics: Gain Bandwidth and Phase Margin vs. Load"). In applications where the load capacitance reduces the speed of the op amp to an unacceptable level, the effect of the load capacitance can be reduced by adding a small resistor (<100 $\Omega$ ) in series with the output.

### Feedback Resistor Selection

Conventional op amp gain configurations and resistor selection apply, the MIC913 is NOT a current feedback device. Resistor values in the range of 1k to 10k are recommended.

#### **Layout Considerations**

All high speed devices require careful PCB layout. The high stability and high PSRR of the MIC913 make this op amp easier to use than most, but the following guidelines should be observed: Capacitance, particularly on the two inputs pins will degrade performance; avoid large copper traces to the inputs. Keep the output signal away from the inputs and use a ground plane. It is important to ensure adequate supply bypassing capacitors are located close to the device.

### **Power Supply Bypassing**

Regular supply bypassing techniques are recommended. A  $10\mu$ F capacitor in parallel with a  $0.1\mu$ F capacitor on both the positive and negative supplies are ideal. For best performance all bypassing capacitors should be located as close to the op amp as possible and all capacitors should be low ESL (equivalent series inductance), ESR (equivalent series resistance). Surface-mount ceramic capacitors are ideal.

### **Thermal Considerations**

P

The SOT-23-5 package, like all small packages, has a high thermal resistance. It is important to ensure the IC does not exceed the maximum operating junction (die) temperature of 85°C. The part can be operated up to the absolute maximum temperature rating of 125°C, but between 85°C and 125°C performance will degrade, in particular CMRR will reduce.

A MIC913 with no load, dissipates power equal to the quiescent supply current \* supply voltage.

$$D(\text{no load}) = (V_{V+} - V_{V-})I_S$$

When a load is added, the additional power is dissipated in the output stage of the op amp. The power dissipated in the device is a function of supply voltage, output voltage and output current.

$$P_{D(output stage)} = (V_{V+} - V_{V-})I_{OUT}$$

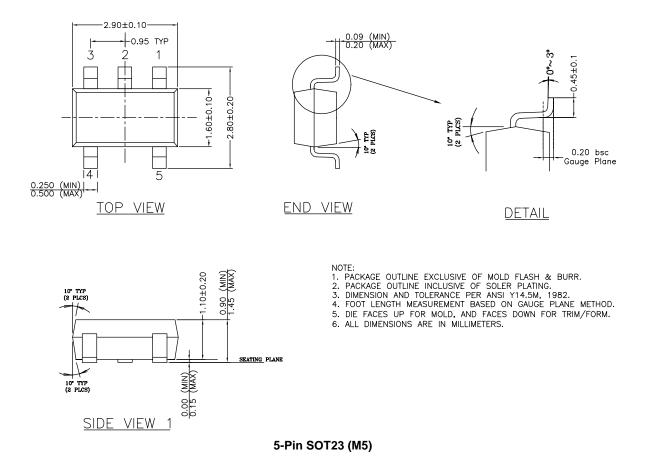
Total Power Dissipation = P<sub>D(no load)</sub> + P<sub>D(output stage)</sub>

Ensure the total power dissipated in the device is no greater than the thermal capacity of the package. The SOT23-5 package has a thermal resistance of 260°C/W.

Max. Allowable Power Dissipation = 
$$\frac{T_{J(max)} - T_{A(max)}}{260W}$$

**MIC913** 

## **Package Information**



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